Zibo Seno Electronic Engineering Co., Ltd.



KMB12S - KMB125S

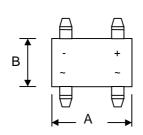


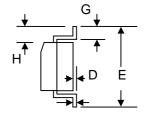


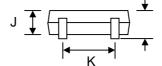
1.0A SURFACE MOUNT SCHOTTKY BARRIER BRIDGE RECTIFIER

Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage Application
- Plastic Case Material has UL Flammability Classification Rating 94V-O







Mechanical Data

Case: MB-S, Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: As Marked on Case
Weight: 0.22 grams (approx.)

Mounting Position: Any Marking: Type Number

Lead Free: For RoHS / Lead Free Version

MB-S								
Dim	Min	Max						
Α	4.50	4.95						
В	3.60	4.10						
С	0.15	0.35						
D		0.20						
Е	6.40	7.00						
G	0.50	1.10						
H	1.30	1.70						
J	2.30	2.70						
K	2.30	2.70						
L	_	3.00						
All Dimensions in mm								

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	KMB 12S	KMB 13S	KMB 14S	KMB 15S	KMB 16S	KMB 18S	KMB 110S	KMB 115S	KMB 120S	KMB 125S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	20	30	40	50	60	80	100	150	200	250	>
RMS Reverse Voltage	VR(RMS)	14	21	28	35	42	56	70	105	140	175	V
Average Rectified Output Current @T _L = 90°C	lo	1.0									Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	İFSM	30									А	
Forward Voltage @I _F = 1.0A	VFM	0.50			0.	0.70 0.		.85 0.9		90	0.92	V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	IRM	0.1 20								mA		
Typical Thermal Resistance (Note 1)	$R_{ heta}$ JL $R_{ heta}$ JA	10 50								°C/W		
Typical Junction Capacitance	Cj	110 30 110							pF			
Operating Temperature Range	Tj	-65 to +150								°C		
Storage Temperature Range	Тѕтс	-65 to +150								°C		

Note: 1. Mounted on P.C. Board with 5.0mm² copper pad area.